# "APPROVED FOR RELEASE: 08/25/2000

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EMT(1)/EWT(m)/EEC(b)-2/EED-2/T/EWP(t)/EWP(b) IJP(c)/SSD/SSD(c)/BSD/ AFWL/ASD(a)-5/AS(mp)-2/AFETR/ESD(dp)/ESD(gs)/ESD(t)
ACCESSION NR: AP4044654 \$/0048/64/028/008/1360/1366 Ŕ AUTHOR: Spivak, G.V.; Shishkin, B.B.; Michurina, K.A.; Khabel, V. TITLE: On the quantitative investigation of efficient emitters in a wide temperature range by observation of contrast in the electron-optical image Report, 11th All-Union Conference on Cathode Electronics held in Kiev, 11-18 Nov 1963/ SOURCE: AN SSSR. IZV. Seriya fizicheskaya, v.28, no.8, 1964, 1360-1366 TOPIC TAGS: emitter, electron emission, electron microscopy, electron optics, cathode ABSTRACT: The present work was a continuation of a series of studies by the authors of emitters and surface emission by means of various electron-optical techniques. The authors' earlier analysis of contrast formation in an electron-optical image of an emitter is generalized to the case of nonuniform efficient cathodes. The results provide the basis for interpretation of data on local emission, taking into account various factors. For the present study there was unsed an electronic circuit that made possible rapid measurement of local currents from a whole region of the emitter, rather than from a point. The formation of (phase) contrast under the influence 1/3

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ACCESSION NR: AP4044654

of different factors (microfields, patch fields, photoemission, secondary emission, etc.) is discussed and the pertinent formulas are adduced. A block diagram of the emission electron microscope used for the study is shown in the Figure (Enclosure). A number of photographs of emitter surfaces are reproduced in the text. By means of the developed oscillographic procedure it should be feasible to perform rapid analyses of various cathodes in different stages of preparation. "The sutbors are grateful to A.M.Rozenfel'd for assistance in rebuilding the emission microscope."
Orig.art.has: 10 formulas and 5 figures.

ASSOCIATION: Fizicheskiy fakultet Moskovskogo gosudarstvennogo universiteta (Physics Department, Moscow State University)

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SUB CODE: EC EM

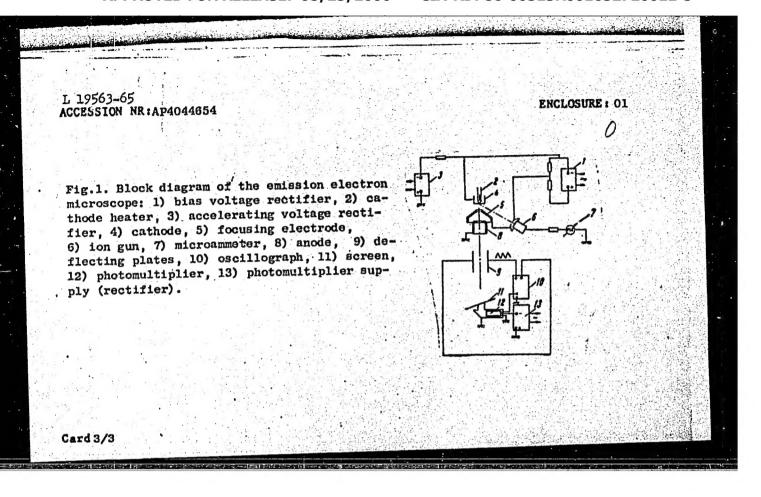
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AUTHOR: Spivak, G.V.; Luk'yanov, A.Ye.; Abalmazova, M.G.

B

TITLE: Observation of local contaminant films by means of a mirror electron microscope Report, 11th All-Union Conference on Cathode Electronics held in Kiev, 11-18

Nov 19637

SOURCE: AN SSSR. Izv. Seriya fizicheskaya, v.28, no.8, 1964, 1382-1386

TOPIC TAGS: electron emission, electron microscopy, contamination, vacuum system

ABSTRACT: The present study is one of an extensive series of investigations by the authors' group of emitter surfaces, microfields, p-n junctions and so on, by means of electron microscopes. The aim of the present work was direct visualization of local deposits consisting of contaminant films of the type that form in vacuum systems with an electron beam by means of a mirror electron micrisope. A common feature of electron mirror images are dark spots, which, it has been found, may represent dust particles or other protrusions on the specimen, local variations of the contact difference of (patch fields), local oxide films, other films of various contaminants (remaining on the surface owing to inadequate cleaning of the specimen) or films

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settling on the specimen surface in the vacuum installation (oil, vacuum grease, rubber vapor and other organic substance films). Thus, the purpose of the present study was to distinguish and investigate films of the last two types (the first two types can readily be identified for they do not disappear as a result of heating the specimen to 200-300°C). Several micrographs of typical contaminant films (spots) are reproduced. Some of their features are discussed. The results obtained indicate that it is feasible by means of an electron mirror microscope to detect and identify dielectric films only a few Angstroms thick and that the sensitivity of the electron mirror procedure is not inferior to that of the method of post-charge emission described by P.N.Chistyakov (Zhur.tekh.fiz.33,1395,1963). Orig.art.has: 5 figures.

ASSOCIATION: Fizicheskiy fakultet Moskovskogo gosudarstvennogo universiteta (Physics Department, Moscow State University)

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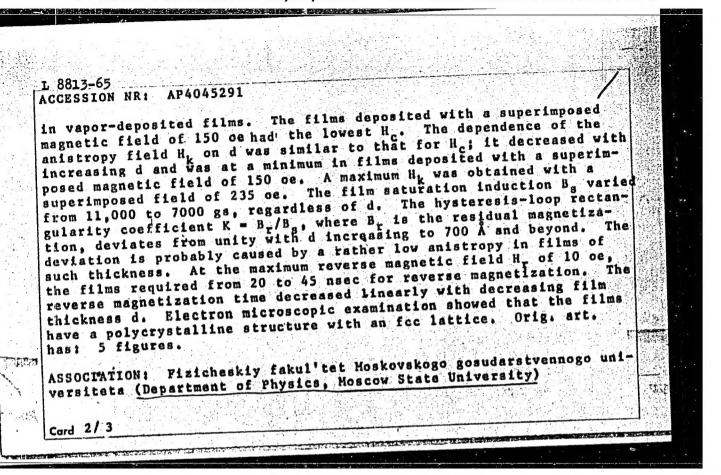
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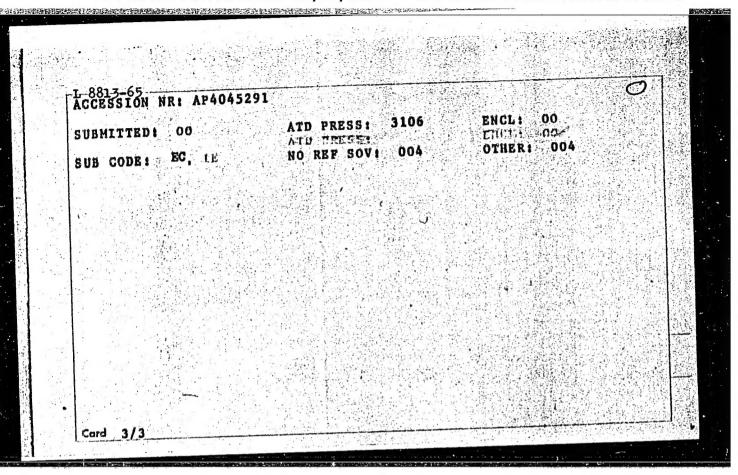
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EWT(1)/EWG(k)/EWT(m)/EPA(Bp)-2/EPF(n)-2/EPA(W)-2/T/EEC(b)-2/ EWA/EWP(q)/EWP(b) Pz-6/Pab-24/Pad/Pu-4 IJP(c)/AFWL/ASD(a)-5/ESD(dp)/ 5/0048/64/028/009/1411/14158 ESD(t)/RAEM(t) JD/HW/GG/AT ACCESSION NR: AP4045291 AUTHOR: Spivak, G. V. (Doctor of physiocomathemetical sciences); Yurasova, V. Ye.; Rozhkova, O. A.; Nikitina, T. N. TITLE: Properties of thin Permalloy films obtained by cathodic sputtering AN SSSR. Izvestiya. Seriya fizicheskaya, v. 28, no. 9, 1964, SOURCE: 1411-1415 TOPIC TAGS: thin film, thin Permalloy film, cathode sputtered film, sputtered film magnetic property ABSTRACT: A study has been made of the magnetic characteristics (important for the magnetic memory-element operation); of thin Permalloy [792 Ni] films, varying in thickness from 300 to 1000 A, deposited by cathodic sputtering on a glass substrate at 2000 with a magnetic field superimposed in the substrate plane. The results of the study showed that the coercive force Hc decreases with increasing film thickness d. The rate of decreases is similar to, but higher than, that observed Card



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AUT	HOR: Krokhina, A.I.; Spivak, G.V.	
Con	TLE: Disintegration of ceramics and glasses under ion bombardment/Report, Tenth inference on Cathode Electronics held in Kiev, 11-18 Nov 1963	
TOR ARS bor vic ia: F.1 we: si:	PIC TAGS: ion bombardment, glass, ceramic, surface geometry, structural property STRACT: The destruction of the surfaces of glass and ceramic materials by ion mbardment is discussed in general terms on the basis of experimental material precously published by G.V.Spivak and collaborators, and some new experimental material. The samples were bombarded in an apparatus previously described by G.V.Spivak, I. The samples were bombarded in an apparatus previously described by G.V.Spivak, F.Kushnir and V.Ye.Yurasova (Izv.AN SSSR,Ser.fiz.23,744,1959; 25,707,1961) and F.Kushnir and V.Ye.Yurasova (Izv.AN SSSR,Ser.fiz.23,744,1959; 25,707,1961) and the heated to temperatures as high as 1200°C. The discussion is illustrated with a control and electron micrographs of bombarded surfaces. In some cases a grain cructure could be perceived on the surface, the regions between the grains being coded to a different extent than the grains themselves. Obliquely incident ions coduced furrows having nothing to do with the structure of the material. It is	

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concluded that features of the	eroded surface are frequently du	ue to the uneven i	on ra-
current distribution arising	Trom an uneven distribution	t ceramics, and pa	*- 4
of the gouttered specimen, and	6A1Geuce or and cramators	a can be perceived	10
the damaged surface. Orig.art	"Uss: 9 TIRmes.		
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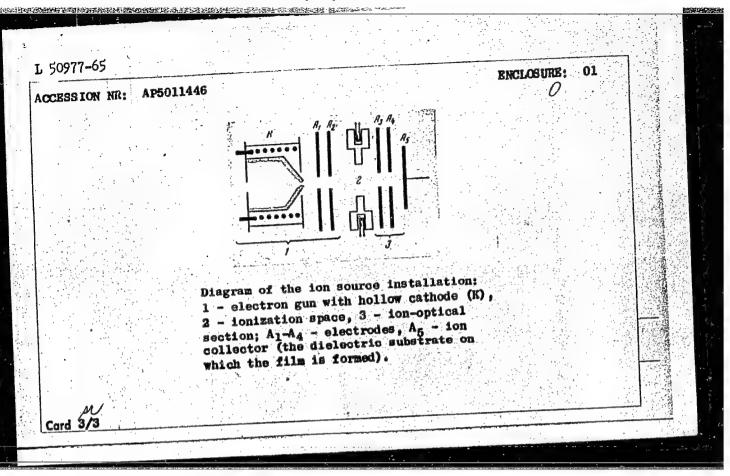
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. 1	ACCISSION NR: AP5011445		
	AUTHOR: Pavlyuchenko, O. P.; Spivak, G. V.; Shakmanov, V. V.		
	TITLE: Concerning thin films prepared by cathod sputtering of ferrites Report, Second All-Union Symposium on the Physics of Thin Ferromagnetic Films held in		
	Talontak 10-15 JULY 1907/ A.		
	SOURCE: AN SSSR. Izvestiya. Seriya fizicheskaya, v. 29, no. 4, 1965, 626-628		
	monto TAGS: ferromagnetic thin film, ferrite, cathode sputtering		
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	structure of the starting ferrites. The films were deposited on polished gases structure of the starting ferrites. The films were deposited on polished gases on cleaved NaCl. Films of optimum thickness (300 Å) were examined in a transmitted on cleaved NaCl.		
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Some of the diffraction was realized in a setup discharge in xenon at a	; in addition, electron diffraction patterns and micrographs are reproduith a thermal cathode providing an pressure of $5 \times 10^{-3}$ torr. The spective of their high resistance the interpretable of the second se	intense (about 3 A) cimen was connected at ferrite specimens were	
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UR/0048/65/029/004/0629/0633 56	
ACCESSION NR: AP5011446	
ACCESSION NR: APSOLITATE  AUTHOR: Dubinina, Ye.M.; Pyt'yeva, M.B.; Spivak, G.V.; Makhmud Eldin Saad  2	1. 经债
AUTHOR: Dubinina, Ye.M.; Pyt. yeva, a. D.	(A) 2
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AUTHOR: Dubinina, Ye.M.; Fye Journal of a high-vacuum ion source TITLE: On formation of Permalloy films by means of a high-vacuum ion source TITLE: On formation Symposium on the Physics of Thin Ferromagnetic Films	
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TITLE: On formation of Permalloy films by means of a high-vacuum lon source.  Report, Second All-Union Symposium on the Physics of Thin Ferromagnetic Films  Report, Second 10-15 July 1964/	198
Report, Second All July 1964/ held in Irkutsk 10-15 July 1964/	
netu 11 29, no. 4, 1965, 629-633	
held in Irkutsk 10-15 July 1552 SOURCE: AN SSSR. Izvestiya. Seriya fizicheskaya, v. 29, no. 4, 1965, 629-633	
SOURCE: AN SSSR. 1200007	
TOPIC TAGS: ferromagnetic thin film, permalloy, ion source	14 C 23
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ABSTRACT: The purpose a high-vacuum ion source. In principal and fouration without	
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ABSTRACT: The purpose of the work was the potentiality of automation for purposes of series production without thin films by means of a high-vacuum ion source. In principle the technique thin films by means of a high-vacuum ion source. In principle the technique without thin films by means of any desired thickness and configuration without should allow of preparing films of any desired the production of a mask and without danger of extraneous impurities. Moreover, the ion-use of a mask and without danger of extraneous impurities.	
should and without danger of extraneous for purposes of series produc-	
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ACCESSION NR: AP5011446		
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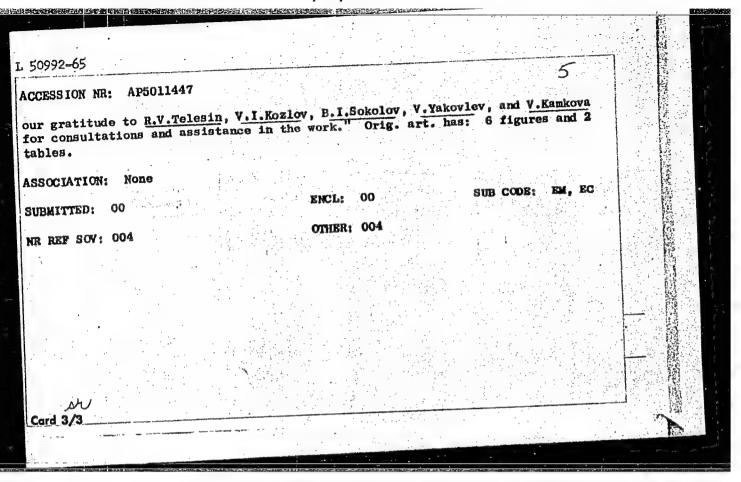


L 50992-65 FWT(1)/EPA(s)-2/EAT(m)/EMP(1)/EMP(t)/EMP(t)/EEC(b)-2/EMP(z)/EMP(b) 3  RT-7/PI-II 1JP(c) JD/G3 UR/0048/65/029/004/0634/0638  ACCESSION NR: AP5011447  AUTHOR: Spivak G.V.; Shelyakin, L.B.; Nikitina, T.N.; Yurasova, V.Ye.; Filippova, T.F.;  Prokhorov, Yu.A.  TITLE: Magnetic properties of Permalloy films formed in ion bombardment /Report, Second All-Union Symposium on the Physics of Thin Ferromagnetic Films held in  Irkutsk 10-15 July 1964/  SOURCE: AN SSR. Izvestiya. Seriya fizicheskaya, v. 29, no. 4, 1965, 634-638  TOPIC TAGS: ferromagnetic thin film, permalloy, magnetic property  ABSTRACT: The work was undertaken in view of the growing use of thin films in electronics and the consequent need for new and better film preparation techniques. Preparation of films by ion bombardment has a number of distinctive features and Preparation of films by ion bombardment has a number of distinctive features and Preparation of films by ion bombardment has a number of distinctive features and Preparation of films by ion bombardment has a number of distinctive features and Preparation of films by ion bombardment has a number of distinctive features and Preparation of films by ion bombardment has a number of distinctive features and Preparation of films by ion bombardment has a number of distinctive features and Preparation of films by ion bombardment has a number of distinctive features and Preparation of films by ion bombardment has a number of distinctive features and Preparation of films by ion bombardment has a number of distinctive features and Preparation of films by ion bombardment has a number of distinctive features and Preparation of films by ion bombardment has a number of distinctive features and Preparation of films formed in ion bombardment has a number of distinctive features and Preparation of films formed in ion bombardment has a number of distinctive features and Preparation of films formed in ion bombardment has a number of distinctive features and Preparation of films formed in ion bombardment has	
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ACCESSION NR: AP5011447  AUTHOR: Spivak, G.V.; Shelyakin, L.B.; Nikitina, T.N.; Yurasova, V.Ye.; Filippova, T.F.;  Prokhorov, Yu.A.  TITLE: Magnetic properties of Permalloy films formed in ion bombardment Report,  Second All-Union Symposium on the Physics of Thin Ferromagnetic Films held in  Irkutsk 10-15 July 1964/  SCURCE: AN SSSR. Izvestiya. Seriya fizicheskaya, v. 29, no. 4, 1965, 634-638  SCURCE: AN SSSR. Izvestiya. Seriya fizicheskaya, v. 29, no. 4, 1965, 634-638  TOPIC TAGS: ferromagnetic thin film, permalloy, magnetic property  ABSTRACT: The work was undertaken in view of the growing use of thin films in  ABSTRACT: The work was undertaken in view of the growing use of thin films in  electronics and the consequent need for new and better film preparation techniques.  electronics and the consequent need for new and better film preparation techniques.  electronics and the consequent need for new and better film preparation techniques.  electronics and the consequent need for new and better film preparation techniques.  electronics and the consequent need for new and better film preparation techniques.  electronics and the consequent need for new and better film preparation techniques.  electronics and the consequent need for new and better film preparation techniques.  electronics and the consequent need for new and better film preparation techniques.  electronics and the consequent need for new and better film preparation techniques.	
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the film and impair its properties. In the present experiments a series of films of different types of Permalloy were prepared in glow and are discharges in an inert gas atmosphere. The orienting field was provided by a pair of Helmholtz coils. The substrates were glass, glass precoated with quartz, aluminum, aluminum cleansed by ionic etching, and rock salt. The substrates were washed before iny stallation in the apparatus and then further cleansed by the discharge before deposition of the films. The films were investigated as regards some of their magnetic properties and subjected to chemical analyses for comparison with the analytic composition of the initial sputtered materials. Electron micrographs and electron diffraction patterns (one of each is reproduced) indicate that the Permalloy films were polycrystalline with a fine-crystal structure. The films on uncleansed Al were of poor quality, but those on cleansed Al were similar to films deposited on glass. Some magnetic data on the films, including curves of the inverse switching time versue switching field, are given in tables and figures. The results show that given proper control of the sputtering conditions and parameters it is feasible to prepare by this technique Permalloy films with characteristics similar to those of films prepared by thermal evaporation; the attainable reproducibility is satisfactory: for example, the scatter of coercive force values in a series of films was less than 10%.



UR/0048/66/030/005/0749/0753 IJP(c) EWI(1) 27641-66 ACC NR: APG015756 (A. N) 16 AUTHOR: Spivak, G.V.; Dyukov, V.G.; Sedov, N.N.; Nevzorov, A.N. ORG: Physics Department, Moscow State University im. M.V.Lomonosov (Fizicheskiy fakultet Moskovskogo gosudarstvennogo universiteta) TITLE: Observation of transient processes in silicon diodes by means of a stroboscopic emission microscope /Report, Fifth All-Union Conference on Electron Microscopy held in Sumy 6-8 July 1965/ SOURCE: AN SSSR. Izvestiya. Seriya fizicheskaya, v. 30, no. 5, 1966, 749-753 TOPIC TAGS: electron microscopy, silicon diode, pn junction ABSTRACT: In the introductory paragraphs note is made of the advantages of employing a stroboscopic or gating electron microscope for studying transient processes in semiconductors and observing the dynamics of microfields. In the work described in the present paper the stroboscopic microscope diagramed in the preceding report by the authors (see Abstract AP6015755) was used to observe the individual phases of establish ment of direct current flow in silicon diodes. It is pointed out that the time resolution of the given electron microscope approaches the nanosecond range. A special simple resistance-capacitance circuit with a vacuum tube was employed to provide the

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SOURCE CODE: UR/0032/66/032/002/0262/0263

AUTHOR: Spivak, G. V.

ORG: none

TITE: Fifth Conference on Electron Microscopy

SOURCE: Zavodskaya laboratoriya, v. 32, no. 2, 1966, 262-263

TOPIC TAGS: optic conference, electron microscopy, germanium, silicon, microscope, lead compound, sulfide, selenide, cadmium sulfide, ferromagnetic material, exitaxial growing, PN junction, crystallization, polymer, semiconductor device

ABSTRACT: Applications of electron microscopy in physical, chemical, metallurgical, technological, biological and medical fields, electron optics and instrument manufacture were the general topics of about 250 papers presented at the Fifth Conference on Electron Microscopy. The conference was held 6-9 July 1965 in Sumy. In the field of physics, papers on the structure of thin films were of scientific interest. Papers in this category discussed the effect of electron irradiation on the crystal structure of vacuum condensed germanium and silicon (A. N. Pilyankevich, V. P. Zakharova, and V. N. Chugayev); formation of chemically deposited lead sulfide and

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L 24125-66 ACC NR: AP6008071 lead selenide films (V. N. Vertsner, L. N. Biller, et al.); epitaxial growth of various (unnamed) films (L. S. Palatnik, V. M. Kosevich, V. M. Moskalev, et al.); vacuum condensation of CdS films (R. D. Ivanov, B. D. Galkin, V. N. Bunarev, et al.); and structure of thin ferromagnetic films (L. V. Kirenskiy of the Krasnoyarsk Institute of Physics, Siberian Department, AS USSR). In the series of papers on instrument manufacture and electron optics, P. A. Stoyanov, E. A. Shulyak, V. N. Kaplichnyy, and other staff members of the Sumy Plant of Electron Microscopes and Electrical Automatic Equipment discussed an improved version of the UEMV-100 microscope; V. S. Gurin, G. D. Kisel', and V. M. Yaremenko reported on a new MES-100 microscope. In the chemistry section, a study of great scientific interest was presented by G. I. Distler on the structure of the p-n junction in semiconductors by means of newly developed decoration techniques. Papers were also noted on a recently developed method of low-temperature etching to reveal morphological forms of polymers (V. M. Luk'yanovich), and Card 2/3

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IJP(c) JD/JH EWT(m)/EWP(e)/EWP(t)/ETI/EWP(k) SOURCE CODE: UR/0226/66/000/005/0067/0073 L 33142-66 AP6015352 (N)ACC NR AUTHOR: Gladneva, L. I. (Moscow); Yefremenkova, V. I. (Moscow); Lebedeva, L. S. (Moscow); Spivak, G. V. (Moscow); Shelamov, V. A. (Moscow); Yurasova, V. Ye. (Moscow) B TITLE: Ascertaining the structure of sintered materials of the He-HeO system by ion bombardment. Report presented at the Fifth All-Union Conference of Electronic Microscopy in Sumy, July 1965 SOURCE: Peroshkovaya metallurgiya, no. 5, 1966, 67-73 TOPIC TAGS: metal oxide system, sintered aluminum powder, powder metallurg, metal poster, electron microscopy, ion bombardment ABSTRACT: A study of the structure of sintered aluminum powder material by ion bombardment is of practical significance for the investigation of materials obtains by means of powder metallurgy. The method is suggested for use for manufacturing samples prior to electron-microscopic investigations. Analysis of microphotographs shows that the base of SAP material is a cellular grid consisting, of oxide particle bounded by aluminum pseudograins. Orig. art. has: 8 figures. [Based on author's abstract.] SUB CODE: 11, 20/ SUBM DATE: 11 Aug65/ ORIG REF: 002/ OTH REF: 001 15 1/1 Card

# "APPROVED FOR RELEASE: 08/25/2000

CIA-RDP86-00513R001652720012-5

L 27642-66 EWT(1) IJP(c)
ACC NRAP6015755 (A, N)

SOURCE CODE: UR/0048/66/030/005/0742/0748

48.

AUTHOR: Spivak, G.V.; Dyukov, V.G.; Sedov, N.N.: Nevzorov, A.N.

ORG: Physics Department, Moscow State University im. M.V.Lomonosov (Pizicheskiy fakultet Moskovskogo gosudarstvennogo univesiteta)

TITLE: A stroboscopic secondary-emission electron microscope / Report, Fifth All-Union Conference on Electron Microscopy held in Sumy 6-8 July 1965/

SCURCE: AN SSSR. Izvestiya. Seriya fizicheskaya, v. 30, no. 5, 1966, 742-748

TOPIC TAGS: electron microscope, electron microscopy, silicon diode

ABSTRACT: The purpose of a stroboscopic or gating electron microscope is to observe the successive quasi-instantaneous stages of dynamic processes; if the frequency of the investigated process is synthronized with the gating there will be obtained stationary images of the surface structure regardless of the frequency characteristics of the screen. In the case of an emission system with a three-electrode objective a stroboscopic regime can be realized in different ways: supply of the microscope with high-voltage pulses, modulation of the potential on the focusing electrode, or deflection of the beam by means of appropriate deflecting plates. In the instrument employed in the present work pulse modulation was employed (V.G.Dukov, G.V.Spivak, N.N.Sedov, and V.V.Evdokimov, Proc. III Europ. Reg. Conf. on Electron Microscopy, V.A., p. 283, and V.V.Evdokimov, Proc. III Europ. Reg. Conf. on Electron Microscopy, V.A., p. 283, and V.V.Evdokimov, Proc. III Europ. Reg. Conf. on Science and associated electronic equipment

Card 1/3

# ACC NR: AP6015755

Block diagram of the stroboscopic secondary emission microscope with high time resolution: 1) microscope column, 2) specimen with thermocouple and heater, 3) optics of the apparatus, 4) pulsed ion gun, 5) screen and secondaryelectron multiplier, 6) highvoltage rectifier (0 to 50 kV), 7) 5 kV rectifier for the ion source. 8) power supply for the pulse amplifier, 9) strobe pulse amplifier, 10) power supply for ion beam focusing, 11) 5 kV recti fier for the secondary-electron multiplier, 12) wide-band ampli-

fier, 13) oscillograph, 14) generator of shifted pulses, 15) pulse shaping circuit, 16) rectifier supplying bias to the specimen and feeding the shaping circuit 15, 17) rectifier supplying the specimen heater. The section outlined by dashes operates at the high potential.

Card 2/3

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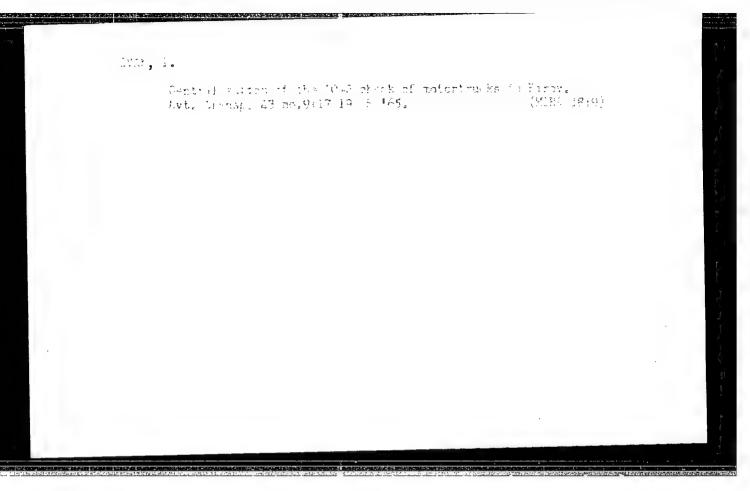
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SPIVAK, Iyan Andreyevich; KAMINSKAYA, N., red.; TROYANOVSKAYA, N., tekhn.
red.

[Descendants of Korchagin] Potomki Korchagina. Moskya, Gos.izd-vo
polit.lit-ry, 1961. 142 p.

(Russia—Social conditions)



SPIVAK, I.I., uchitel'.

How to make vegetable and fruit models. Biol. v shkole no. 3:8688 My-Je '58.

1. Srednyaya shkola No. 9, g. Groznyy.

(Fruit--Models)

(Vegetables--Models)

BLAZHEVSKIY, Ye.V., dvazhdy Geroy Sotsialisticheskogo Truda; VOVCHENKO, I.V., kand. sel'khoz. nauk, zasl. agronom Ukr.SSR; VOROB'YEV, N.Ye., st. nauchn. sotr.; GESHELE, E.E., doktor biol. nauk, prof.; ZUBRITSKIY, A.A., agronom; KISEL'GOF, Z.S., inzh., zasl. mekhanizator sel'skogo khoz. Ukr.SSR; KLYUCHKO, P.F., kand. sel'khoz. nauk; KORCHAGIN, A.Ye.; LEBEDEV, Ye.M., st. nauchn. sotr.; NASYPAYKO, V.M., kand. sel'khoz.nauk; PIKUS, G.P., kand. sel'khoz.nauk; REKACH, V.N., doktor sel'khoz. nauk, prof.; SPIVAK, I.I., zootekhnik; TEMCHENKO, L.V., kand. sel'khoz. nauk; FEDULATEV, A.A., agronom; YAKOVENKO, V.A., kand. tekhn.nauk; KITAYEV, I.A., kand. sel'khoz. nauk, red.; MUSIYKO, A.S., akademik, red.; VINNITSKIY, S.P., red.; MOLCHANOVA, T.N., tekhn. red.

[For high corn yields] Za bol'shuiu kukuruzu. [By] E.V. Blazhevskii i dr. Odessa, Odesskoe knizhnoe izd-vo, 1962. 173 p. (MIRA 16:7)

1. Zven'yevoy kolkhoza im. Gor'kogo Kotovskogo rayona na Odesshchine (for Blazhevskiy). 2. Glavnyy agronom sovkhoza "Bessarabskiy" (for Korchagin). 3. Ukrainskaya akademiya sel'skokhozyaystvennykh nauk (for Musiyko). (Ukraine—Corn (Maize))

SPIVAK, I.I., kandidat tekhnicheskikh nauk.

Computation of the luminous intensity of aberrationless lenses with prismatic elements. Svetotekhnika 2 no.3:15-19 My '56.

(MLRA 9:8)

1. Vsesoyuznyy svetotekhnicheskiy institut. (Lenses)

SPIVAK, I.I., kandidat tekhnicheskikh nauk.

To the editor of "Svetotekhnika." Svetotekhnika 2 no.3:28 My '56.
(Optics)

(Optics)

SPIVAK, I.1., kand.tekhn.nauk

Structure of light beams of two-lens systems. Svetotekhnika 3
no.10:16-20 0 '57. (MIRA 10:10)

1. Vnesoyuznyy svetotekhnicheskiy institut. (Beacons)

SPIVAK, I.I., kand.tekhn.nauk

Calculating light intensity of binary lens systems. Swetotekhnika
4 no.11:16-20 I '58. (MIRA 11:11)

1. Vsesoyuznyy svetotekhnicheskiy institut.

(Lenses)

SPIVAK, I.I., kand.tekhn.nauk

"Luminaires" by V.V.Trembach. Reviewed by I.I.Spivak. Syetotekhnika-I. no.7:31 J1 "59.

(MIRA 12:9)

(Itighting—Equipment and supplies)

(Trembach, V.V.)

SPIVAK, Izrail' Moiseyevich; TYUMENEVA, S.T., inzh., red.; FREGER, D.P., tekhn.red.

[An electric-light instrument for checking screw threads]
Electrosvetovoi pribor dlia kontrolia rez'b. Leningrad, 1956.
2 p. (Leningradskii dom nauchno-tekhnicheskoi propagandy.
Informatsionno-tekhnicheskii listok, no.9. Kontrol' kachestva
produktsii) (MIRA 10:12)
(Electric instruments) (Screw threads)

STIPNOT, V. V., and I. P. STIVAK

SPINES

O podbore gorizontal'nogo operentia s shaibami na kontsakh razwakha. (Tekhnika vozdushnogo flota, 1940, no. 7, p. 59-71, tables, diagrs.)

Title tr.: Selection of a horizontal tail surface wit tip fins.

TL504.TL 1940

SC: Aeronautical Sciences and Aviation in the Soviet Union, Library of Congress, 1955.

AYLENTSON, Ye.G.; MA (NON, F.A.) 1 17 19 18, 2018 CIRCUMN, 1.K.

Effect of ultrasonic waves on the formation of carbide grains during the quenching of hardened carbon steel. Fiz. met. i

metalloved. 17 no.4:624-627 Ap 604.

1. Yestestvenno-nauchnyy institut pri Fermskom gosudarstvennom universitete imeni A.M. Gor'kogo.

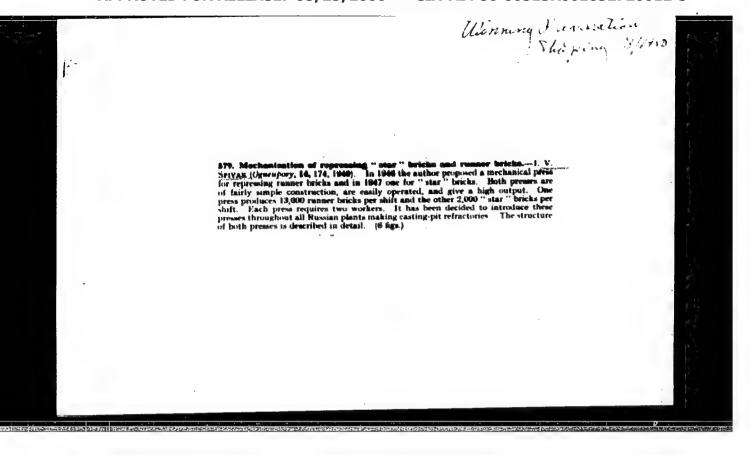
(MIRA 17:8)

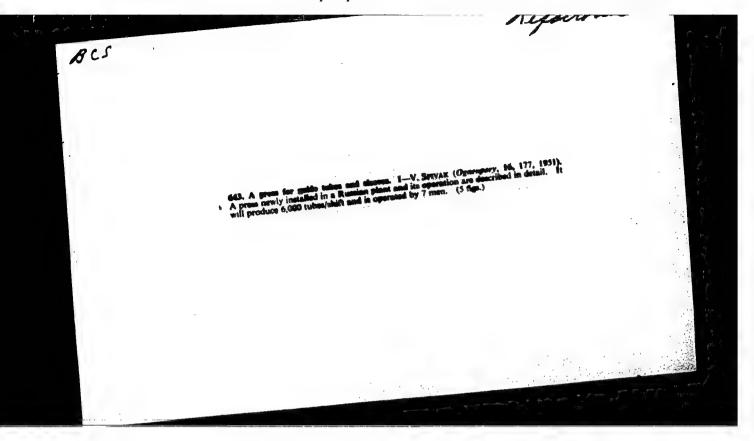
SPIVAK, I. V.

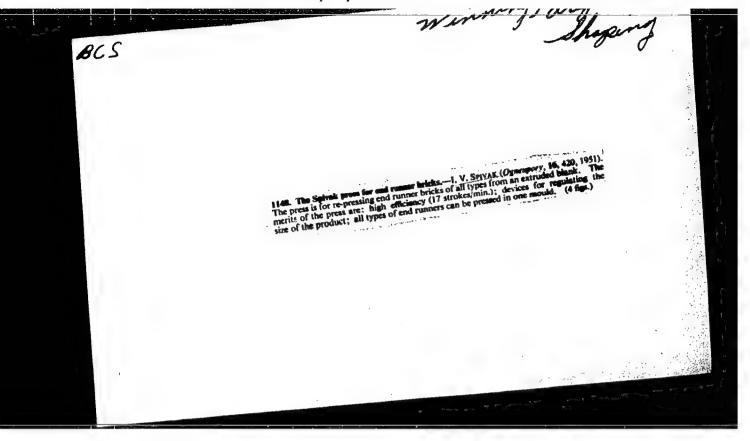
"Mechanizing the Process of Pre-Pressing Star Sprokets and Arch Siphons," Ogneupory, No. 4, 1949.

# "APPROVED FOR RELEASE: 08/25/2000

# CIA-RDP86-00513R001652720012-5

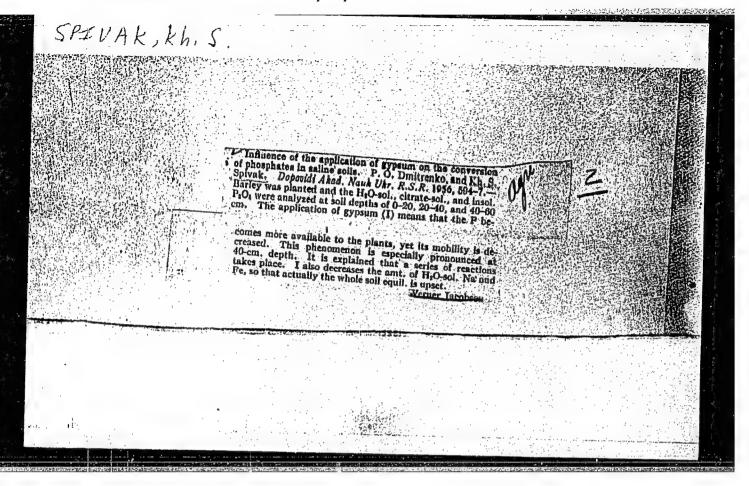






- SPIVAK, FH, S. ı.
- USSR (600) 2.
- Gypsum 4.
- Seasonal dynamics of the salt cycle in soda solonetz soils in Connection with the application of gypsum, Trudy UNDISOZ 6, 1951 7.

9. Monthly List of Russian Accessions, Library of Congress, May



# SPIVAK, Kh.S., kand.sel'skokhoz.nauk Effect of gypsum application to Solonetz soils on the chemical composition of underground waters. Nauch.trudy UASHN 9:19-21 159. (MIRA 14:3) (Gypsum) (Solonetz soils) (Water, Underground)

SPIVAK, L.

Conference of organizations for planning and design and of synthetic fiber plants. Khim.volok no.4:80 162. (MIRA 15:8)

1. Gosudarstvennyy institut po proyektirovaniyu predpriyatiy iskusstvennogo volokma.

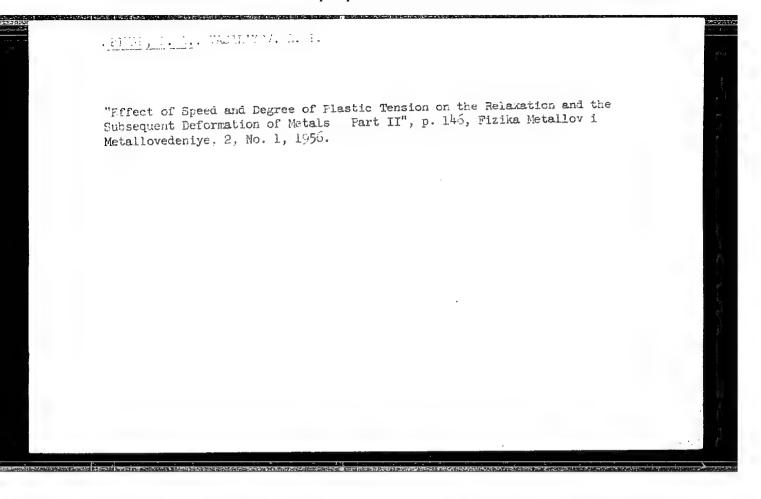
(Textile fibers, Synthetic—Congresses)

NESTERENKO, I., inzh.; SPIVAK, L., inzh.

Design of a large-span roof made of slabs sealed with poured concrete. Prom.stroi.i inzh.soor. 4 no.5:19-24 S-0 '62.

(MIRA 16:1)

(Roofing, Concrete)



SPIVAK, L.A.

Treating paroxysmal tachycerdis with antiepileptics. Vrsch.delo
no.12:1335 D'57.

1. Kafedra fakul'tetskoy terapii (zav. - prof. S.Ya.Shteynberg)
Khar'kovskogo meditainskogo instituta.
(HEART--PAIPITATION)
(AMTISPASMODICS)

# SPIVAK, L.I.

Pendulum-like knee reflex. Nevropat.psikhiat., Moskva 20 no.1:56-57 Jan-Feb 51. (CIML 20:6)

1. Captain, Medical Corps. 2. Of the Department of Psychiatry (Head-Prof.N.I.Bondarev, Major General, Medical Corps), Military Medical Academy imeni S.M.Kirov.

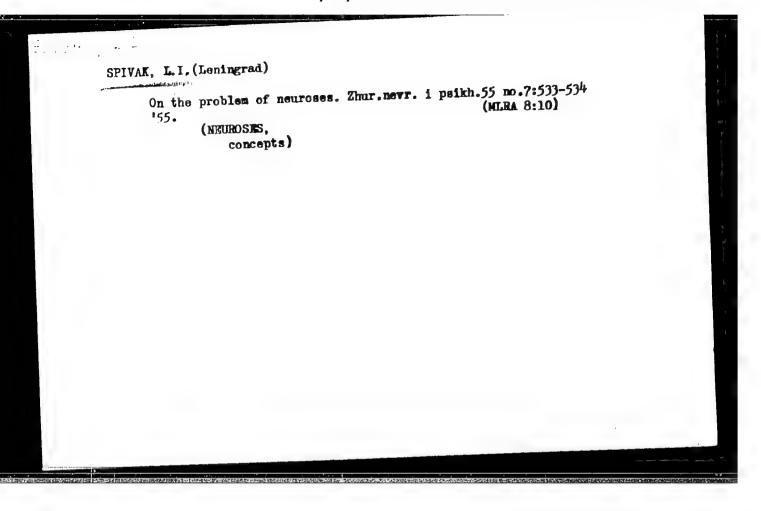
# SPIVAK, L.I.

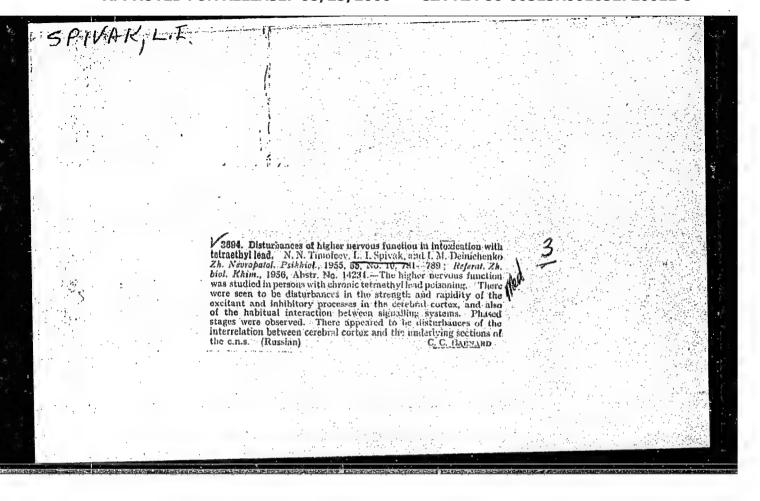
Changes in the knee reflex in depressive and hypomanic states. Zhur.nevr.i. psikh, 53 no.6:422-428 Je '53. (MLRA 6:6)

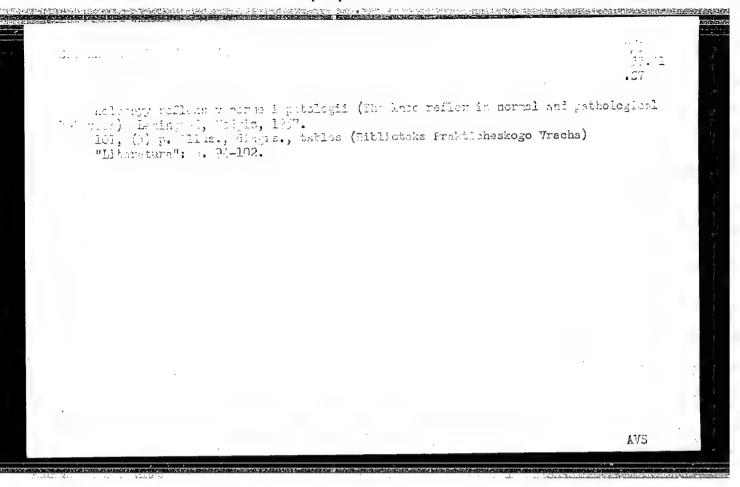
1. Psikhiatricheskaya klinika Voyenno-meditsinskoy akademii imeni S.M.Ki-rova. (Reflexes)

SPIVAK, L. I.

"The Problem of Clinic During Chronic Poisoning With Tetraethyl Lead", Military-Midical Journal, No. 8, p 37, Aug 1955.







# SPIVAK, L.I.

Intraosseous administration of drugs and blood in psychiatric practice.
[with summary in French]. Zhur.nevr. i psikh. 58 no.2:215-217 '58.

(MIRA 11:5)

1. Kafedra psikhiatrii (zav. - prof. A.S. Chistovich) Voyennomeditsinskoy akademii imeni S.M. Kirova.

(MENTAL DISORDERS, therapy,
intra-osseus drug & blood admin. (Rus))
(BLOOD TRANSFUSION,
intra-osseous in psychiatry (Rus))
(BONE AND BONES,
intra-osseous drug &blood admin. in psychiatry (Rus))

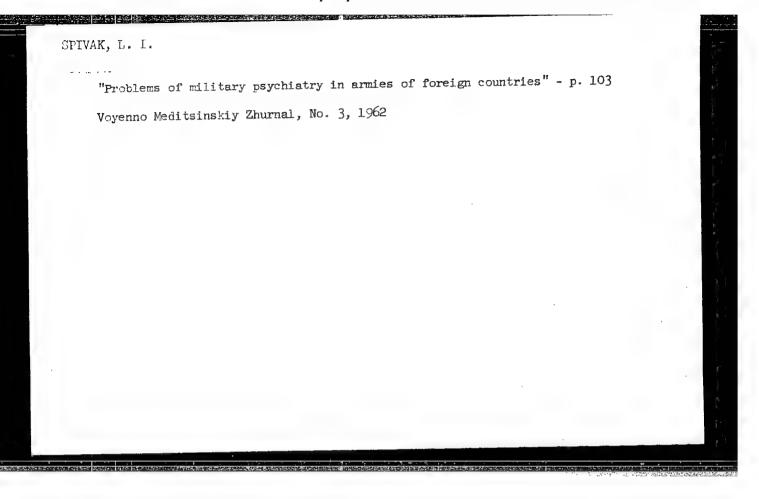
# SPIVAK, L.I.

P.P. Pelekhin's dissertation on "The nature of neuroses"; material on the history of Russian psychiatry. Zhur.nevr. i psikh. 85 no.11:1389-1391 N'58 (MRA 12:1)

1. Kafedra psikhiatrii (nachal'nik - prof. A.S. Chistovich)
Voyenno-meditsinskoy ordena Lenina akademii im. S.M. Kirova.

(PSYCHOSES, history

origin of psychoses, 19th century dissertation (Rus))



## GZECHOSLOVAKIA

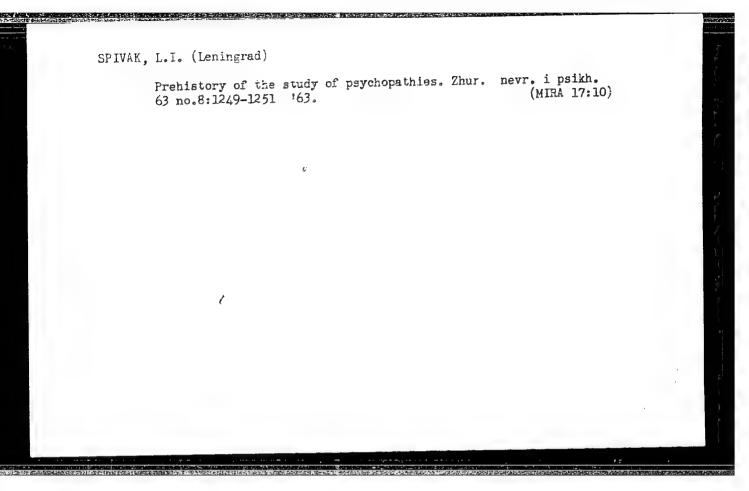
Lt Col of Medical Corps L.I. SPIVAK [USSR Armed Forces?] translated by Lt Col MD Jan HES [affiliation not stated.]

"Problems of Military Psychlatry in Foreign Armies (Review of Foreign Literature.)"

Prague, Vojenske Zdravornicke Listy, Vol 31, No 5, Oct 52; pp 231-232.

Abscreet: Presumably review of published data; no bibliographic ref's tut many Western names interspersed in text. Statements such as "67.3% of US strategic flyers scheduled for transcontinental flights with atom or hydrogen bombs are suffering from neuroses (B. Berri, I. Skebba.)" Most comments pertain to US military experiences in WW II or Korea; nuclear was preparation; brist comments about military action in the tropics.

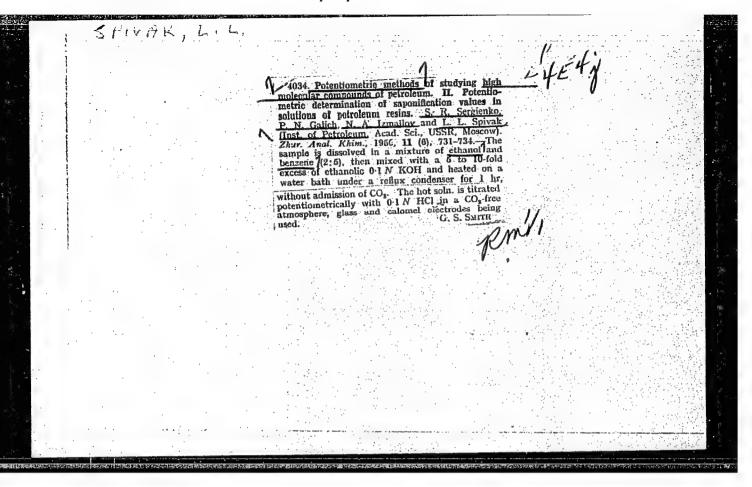
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SERGIYENKO, S.R.; IZMAYLOV, N.A.; SPIVAK, L.L.; GALICH, P.N.

Petentiemetric methods of investigation of high-melecular weight compounds in petroleum. Zhur.anal.khim.lo no.5:315-322 S-0 '55.
(MLRA 9:1)

1. Institut mefti AN SSSR, Meskva i Khar'kevskiy gesudarstvenyy universitet imeni Ger'kege.
(Petentiemetric analysis) (Acidity) (Petroleum)



SPINA	1K , L. (			
	motor metric Servic Petrol Anal. contair 20 mi	Petentiometris methods of studying high- plar petroleum compounds. III. Potentio- determination of peroxide sumbers. S. R., nko, P. N. Galich and L. L. Spivak (Inst. of cum. Acad. Sci., USSR., Moscow). Zhur. Khim., 1037, 12 (1), 139-142.—The sample of absolute isopropyi alcohol and 2 ml of acetic acid and then boiled for 5 min. with	5 4238	
	propyl water electro N gas vessel	alcohol. The soin, is mixed with 6 ml of in a cell containing a platinum indicator le, a connection to a S.C.E. and an inlet for to stir the soin. Alternatively, a closed with a stirrer may be used. Potentiometric in is carried out with 0-1 N Na. S.O.  G. S. SMITH  G. S. SMITH		
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SHIMAY, L.L., Cand Then Del - (die.) Effect of abroton and nized polyents by the relative force of strength of acids." An eller, 1959, 17 pp (Min of Higher Education UK, OR. Physikev Order of Labor Red Fancer State Univ in A.F. Gortkiy) 106 copies (KL, h2-58, 113)

- 11 -

SHKCDIN, A.M.; ALEKSANDROV, V.V.; SPIVAK, L.L.; VAYL', Ye.I.; CHERNYY, V.S.;
TITOV, Ye.V.; IVANOVA, Ye.F.; KRUGLYAK, Yu.A.; RYEKIN, Yu.F.

Nikolai Arkad'evich Izmailov, 1907-1961. Ukr.khim.zhur. 28
no.2:271-282 '62.
(Izmailov, Nikolai Arkad'evich, 1907-1961)

IZMAYLOV, N.A. [deceased]; SPIVAK, L.L.

Thermodynamic properties of electrolytes in nonaqueous solutions.
Part 12. Effect of aprotic solvents on the relative strength of acids. Zhur. fiz. khim. \$6-no.44.757-764 ap '62.

(MIRA 15:6)

1. Khar'kovskiy universitet.

(Solvents) (Acids)

IZMAYLOV, N.A. [decembed]; SHIVAF, 1.1.

Thermodynamic properties of electrolytes in nonameous solutions. Part 13. Thur. fiz. infm. 36 no.621258-1163 Ja+62 (MIRA 1727)

1. \*\*\*cr\*\*kovskiy universit t.

ESD-3 Ps-4/Pc-4/Pr-4 RM/WW/RH/JW EPR/EWT(m)/EWP(j)/EPF(c)/BDS I 16921-63 \$/076/63/037/004/011/029 Izmaylov, N. A. (Deceased), Chernyy, V. S., Spivak, L. L. AUTHOR: Thermodynamic properties of non-aqueous electrolyte solutions. XIV. Calculation of the transport energy of acids from one solvent TITLE: to another Zhurnal fizicheskoy khimii, V. 37, No. 4, 1963, 822-828 PERIODICAL: The values for  $\Delta pK = 1g K_{H20} = 1g K_{M}$  of various acids in alcohols, ammonia, and formic acid are compared with those for lg yo H+, the transolvation energy of the proton. The changes in the transfer energy of acid anions and of non-dissociated acids are calculated from solubility data. On the basis of the results which are obtained an attempt is made to calculate the values for APK from the change in transfer energy of the proton (1g no H), anion (1g no A), and non-dissociated molecules (1g no mol). It is shown that these data may serve for the estimation of the change in strength of the acids on passing from one solvent to another. There are 6 tables. ASSOCIATION: Khar'kovskiy gosudarstvennyy universitet (Kharkov State University) April 14, 1962 SUBMITTED: Card 1/1

ALEKSANDROV, V.V.; SPIVAK, L.L.: ZAKHARCHENKO, L.K. (Khar'kov)

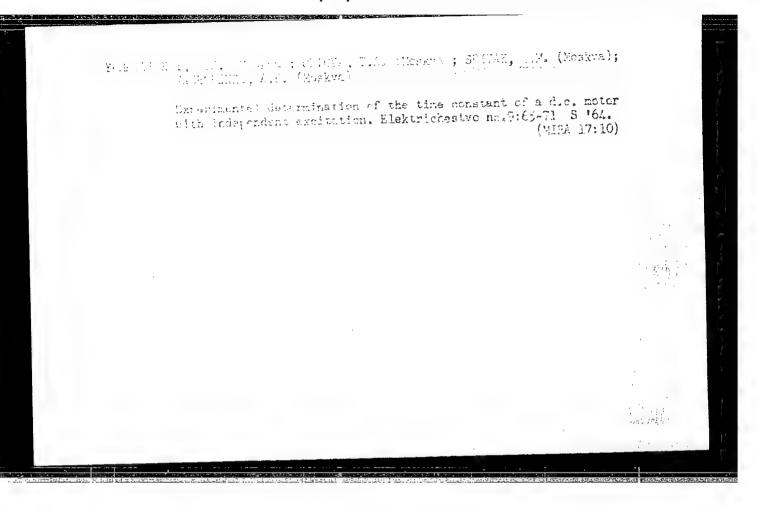
Dissociation constants of some acids in mixed solvents methanolbenzene and methanol-benzene-water. Zhur. fiz. khim. 39 no. 1: 58-63 Ja 165 (MIRA 19:1)

1. Khar'kovskiy gosudarstvennyy universitet imeni A.M. Gor'kogo. Submitted December 14, 1963.

The trochemical measurements in a metranol - benzens - water mixture.

Charafiz.ham. 39 no.7-1585-1589 2 165.

Charafiz.hamskiy gosudarstvennyy universitet, institut mono - kurcusliov.



EWP(r)/EWP(q)/EWT(m)/BDS--AFFTC/ASD/APGC--JD L 10791-63 S/0279/63/000/002/0124/0129 56 ACCESSION NR: AP3000913 AUTHOR: Ayzentson, Ye. G. (Perm'); Spivak, L. V. (Perm') TITLE: Effect of ultrasonic vibrations on the isothermal decomposition of KhVG austenitic steel SOURCE: AN SSSR. Izv. otd. tekh. nauk. Metallurgiya i gornoye delo, no. 2, 1963, 124-129 TOPIC TAGS: austenite decomposition, tool steel, ultrasound effect, residual austenite, hardness ABSTRACT: Specimens (30-mm long, 9 mm in diameter) of KhVG tool steel (0.95% C, 1.1% Mn, 0.24% Si, 1.22% Gr, and 1.58% W), annealed in a salt bath at 1000 or 900C for 20 min, were transferred to other baths with temperatures of 250 or 450C, held for 2 min, and then subjected to ultrasonic vibrations with a frequency of 20.5 kc at amplitudes of 3, 10, or  $18\mu$  applied directly to specimens for 10 to 120 min. In specimens annealed at 1000C, ultrasound at an amplitude of 3, 10, or 18  $\mu$ , applied for 10, 30, 60, or 90 min at 250C, was found to refine martensitic Card 1/32

L 10791-63 ACCESSION NR: AP3000913

structure. The amount of residual austenite and hardness ( $R_c = 62-63$ ) were not affected. Ultrasound at 10 and 18 \mu amplitude, applied at 250C for 60 or 120 min, accelerated the decomposition of austenite in specimens annealed at 900C, while ultrasound at 3 µ amplitude applied under the same conditions delayed the decomposition. In the same specimens, only ultrasound at an amplitude of 18  $\mu$  applied for 60 and 120 min increased the hardness by 2-3 and 5-6  $R_{\rm c}$ . Ultrasound applied for 15 or 30 min at 450C to specimens annealed at 1000C did not affect the decomposition of austenite. Longer (60, 90, or 120 min) treatment with ultrasound at an amplitude of 10 or 18 µ delayed decomposition and increased hardness by 6 to 7 R . Decomposition of austenite in specimens heated to 900C and treated with ultrasound at 450C generally followed a pattern similar to that observed in the previous case, except that decomposition started after treatment for 15 min and hardness increased by only 2-3 R . Ultrasound at a 3µ amplitude accelerated the decomposition. Thus, in isothermal decomposition of austenite, ultrasonic vibrations at an amplitude of 10 or 184 increase the stability of austenite at 450C, but lower it at 250C, while emplitudes of 3H have the opposite effect. Orig. art. has: 5 figures.

Card 2/32

EMT(m)/EMA(d)/T/EMP(t)/EMP(b)/EMP(1)/EMA(h) Peb MJW/JD L 27261-65 5/0126/64/017/004/0624/0627 AUCESSION NR: AP4034064 AUTHORS: Ayzentson, Ye. G.; Malinen, P. A.; Spiyak, L. V.; Utrobina, I. K. TITLE: Effect of ultrasonic oscillations on carbide grain formation during annealing of quenched carbon steel SOURCE: Fizika metallov i metallovedeniye, v. 17, no. 4, 1964, 624-627 TUFIC TAGS: annealing, quenching, ultrasonic vibration, carbon steel/ 1112 steel ABSTRACT: The effect of ultrasonic oscillations on carbide formation was investigated in U12 steels during annealing at 680C. The 10-mm diameter steel specimens were quenched from 960C temperature in oil and screwed on the waveguide of a magnetostrictive vibrator. At 20.5-kc frequency standing waves of 10 M amplitude were created in the specimen. After the test, longitudinal sections were sliced off from the specimen and the microstructure was analyzed at 2000 magnification. After 1 hour of annealing and ultrasonic oscillations, the microstructures indicated, on the average, larger carbide particle sizes with greater distances between each carbide particle than in the control specimens. A graphical plot of the number of carbide particles versus annealing time shows that the effect of

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ACCESSION NR: AP4034064

ultrasonic oscillations first increases, reaches a maximum, and subsequently decreases. For a given test duration time, the particle distribution falls sharply from the end of the specimen until it reaches a constant value at a distance of 40 mm. These results show that ultrasonic oscillations promote coagulation of carbides in Ul2 steels. Orig. art. has: 4 figures.

ASSOCIATION: Yestestvenno-nauchnyy institut pri Permskom gosuniversitete im. A. M. Gor'kogo (Natural Science Institute, Perm State University)

SUBMITTED: 16Apr 63

ENCL: 00

SUB CODE: MM

NO REF SOV: 007

OTHER: OOL

Card 2/2

<u>L 6</u>	3331-65 EMP(k)/EMP(z)/EMA(c)/EMT(1)/EMT(m)/EME(h)/T/EMA(d)/EMP(t) Pf-1/Pi-1/  ACCESSION NR: AP5017472 MJW/JD UR/0370/65/000/003/0123/0127 669.017.3	
3 -	AUTHOR: Ayzentson, Ye. G.; Spivak, L. V.; Utrobina, I. K.	
	TIPLE: Isothermal decomposition of the austenite of KhVG steel in an ultrasonic field	
	SOURCE: AN SSSR. Izvestiya. Metally, no. 3, 1965, 123-127	
÷	TOPIC TAGS: isothermal decomposition, decomposed austenite, supercooled austenite, ultrasonic vibration, bainitic structure	
	ABSTRACT: The present work is a continuation of a previous investigation which showed that ultrasonic vibrations exert a definite and not always unambiguous effect on the decomposition of supercooled austenite of KhVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of KhVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of KhVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of KhVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of KhVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of KhVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of KhVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of KhVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of KhVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of KhVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of KhVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of KhVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of KhVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of KhVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of KhVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of KhVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of KhVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of KhVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of KhVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of khVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of khVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of khVG steel (0.99% C, 0.25% fect on the decomposition of supercooled austenite of khVG steel (0.99% C, 0.25% fect on the decompositio	
	brations with amplitudes of 10 and 15 h Indian These findings were obtained	
	while at 250°C they contribute to its decomposition. Intest intesting the second on the basis of a qualitative comparison of the microstructures and roentgenograms on the basis of a qualitative comparison of the microstructures and roentgenograms on the basis of a qualitative comparison of the microstructures and roentgenograms on the basis of a qualitative comparison of the microstructures and roentgenograms on the basis of a qualitative comparison of the microstructures and roentgenograms on the basis of a qualitative comparison of the microstructures and roentgenograms on the basis of a qualitative comparison of the microstructures and roentgenograms of specimens with and without exposure to the ultrasound. In this connection, it was of interest to investigate the effect of ultrasonic vibrations on the isotherway of interest to investigate the effect of ultrasonic vibrations on the isotherway of the microstructures and roentgenograms.	
	Card 1/2	6

L 63331-65

ACCESSION NR: AP5017472

mal decomposition of austenite over a broader range of temperatures and to establish quantitative ratios. Accordingly the authors exposed specimens of this steel to ultrasonic vibrations with  $18~\mu$  amplitude in salt baths at temperatures of 700, 550, 500, 450, and 300°C. Transverse microsections of the specimens taken at the sites of maximum stresses were subjected to diffraction studies at room temperature The amount of undecomposed austenite was estimated according to the reflexes (111) of austenite and (110) of alpha-phase. In addition, the microhardness of the decomposition products was determined by plotting frequency curves on the basis of measurements for every individual case. Microstructural examination revealed that ultrasonic vibrations in different temperature regions differently affect the austenite. At 700°C they inhibit the decomposition of austenite; at 550°C they lead to a reduction in the amount of residual austenite in specimens cooled to room temperature, while at 450°C they produce an opposite effect, and at 300°C they contribute to the decomposition of austenite. This is attributed by the authors to the mechanism of transformation in each temperature region. For supercooled austenite the effect of ultrasonic vibrations is expressed in the form of a finer bainitic structure. Orig. art. has: 5 figures.

ASSOCIATION: none

SUBMITTED: 02Apr64

ENCL: 00

SUB CODE: MM, SS

NE REF SOV: 001

OTHER: 000

EWT(m)/EWA(d)/T/EWP(t)/EWP(b)/EWP(z)/EWA(h)/EWA(c) Peb MJW/JD L 5511.0-65 UR/0148/65/000/006/0127/0130 AP5015823 ACCESSION NR: 21 669.011.7:621.034.4-8 AUTHOR: Ayzentson, Ye. G.; Spivak, L. V. TITLE: Effect of ultrasonic vibration on austenite grain growth during annealing Chernaya metallurgiya, no. 6, 1965, 127-130 SOURCE: IVUZ. TOPIC TAGS: steel, steel treatment, austenite grain, grain growth, ultrasonic treatment/U12 steel ABSTRACT: The effect of treatment by ultrasonic vibration at 20.5 kc on the grain growth during subsequent annealing in austenite of U12 steel (1.15% C, 0.20% Mn, 0.32% Cr, 0.25% Si) has been investigated. Specimens 10 mm in diameter were treated with ultrasound at 850, 900, or 950C for 10-40 min, air cooled, and then annealed at 900-1200C for 4 hr. It was found that the grain size of specimens treated with ultrasound is, as a rule, larger than that of untreated specimens. Electric resistivity increases under the effect of ultrasound, which weakens grain boundaries and lowers strength and ductility

L 55140-65...

ACCESSION NR: AP5015823

However, subsequent annealing restores the strength and increases the elongation 15—20% over that of untreated specimens. Ultrasonic treatment followed by annealing changes the grain boundaries of austenite and increases the space between pearlitic lamellae. It reduces the rate of austenite grain growth during high-temperature annealing and lowers the microhardness of annealed specimens. The effect of ultrasonic vibration may be explained by the formation of submicroscopic distortions at grain boundaries which absorb various impurities. Orig. art. has: 5 figures.

ASSOCIATION: Yestestvenno-nauchnyy institut pri Permskom gosudarstvennom universitete (Natural-Sciences Institute, Perm State University)

SUBMITTED: 06Ju164

ENCL: 00

SUB CODE: MM

NO REF SOV: 007

OTHER: 000

ATD PRESS: 4025

Card 2/2

ACC NR AP7002547

SOURCE CODE: UR/0413/66/000/023/0027/0027

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INVENTOR: Ayzentson, Ye.G.; Bobrova, S.N.; Spivak, L.V.

ORG: none

TITLE: Method of heat treatment of steel. Class 18, No. 189005

SOURCE: Izobreteniya, promyshlennyye obraztsy, tovarnyye znaki, no. 23, 1966, 27

TOPIC TAGS: METRIL heat treatment, steel normalization, steel ultrasonic treatment, steel refrigeration ANNEALING, COOLING, REFRIGERATION. STEEL STRUCTURE

ABSTRACT: This Author Certificate introduces a method of heat treatment of steel which consists in annealing followed by air cooling and refrigeration. To ensure their dimensional stability, the steel parts are subjected to [ND] sultrasonic treatment prior to refrigeration.

SUB CODE: 13/ SUBM DATE: . 18Jan65 / ATD PRESS: 5113

Card 1/1

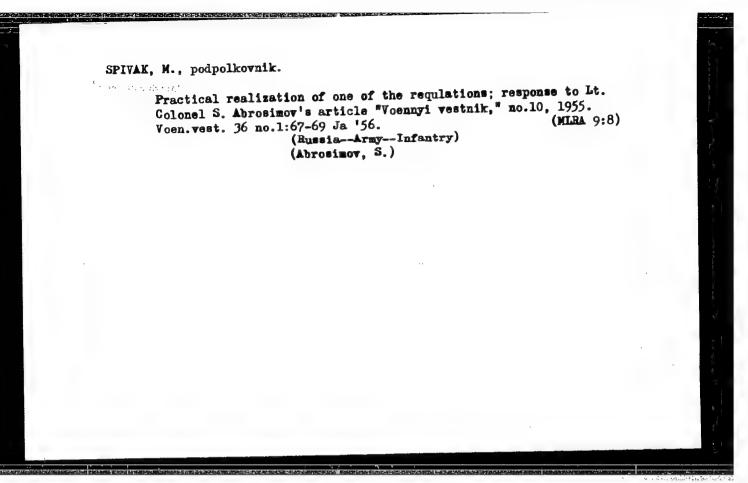
621.785.92:621.9.048.6:621.789

SPIVAK, L.V., starshaya operatsionnaya sestra

Decreasing alcohol consumption in surgery. Klin. khir. no.10:76 0 162. (MIRA 16:7)

1. Kafedra khirurgii (zav.- prof. D.F. Skripnichenko) stomatologicheskogo fakul'teta Kiyevskogo meditsinskogo instituta i 1-ya Podol'skaya klinicheskaya rayonnaya bol'nitsa, Kiyev. (SURGERY, ASEPTIC AND ANTISPETIC) (ETHYL ALCOHOL)

# Monetary payment of wages on collective farms in the Ukraine. Sots. trud 5 no.8:19-25 Ag '60. (MIRA 13:11) 1. Ministr sel'skogo khozyayetva USSR. (Ukraine--Collective farms--Income distribution)



 SPIVAK, M.

Selection of optimal speed in approaching ports and canals. Mor. flot 25 no.7:12 J1 '65. (MIRA 18:7)

1. Kapitan teplokhoda "Murom".

AUTHOR:

Spivak, M.A.

SOV/:40-58-4-26/30

TITLE:

Algebraic Theory of Coordinate Structures and Geometric Objects (Algebraicheskaya teoriya koordinatnykh struktur 1 geometricheskikh ob wsktov)

PERIODICAL: Izvestiya vysshikh uchebnykh zavedeniy. Matematika, 1958, Nr 4, pp 236-247 (USSR)

ABSTRACT:

The author generalizes the notion of a coordinate structure as a set of coordinate systems. He considers the mappings of an arbitrary set A into an arbitrary set B instead of the mappings of the geometric space into an arithmetic space, and he calls the sets of such partial one-to-one mappings atlantes. He forms an axiomatic of certain types of atlantes, where the axioms are set-theoretical properties of the coordinate structures of the spaces of Veblen-Whitehead LBef 37, Klein, etc. Furthermore the geometric objects of Klein and differential-geometric objects (in the sense of Vagner [Ref 4] ) are subordinated to the more general notion of the associated atlantes. Hereby some generalizations of the assertions of Vagner [Ref 4] are obtained. There are 4 references, t of which is Soviet, T French, and

Card 1/2

2 American.

ASSOCIATION: Saratovskiy gosudarstvennyy universitet imeni N.G. Chernyshevskogo (Saratow State University imeni N.G. Chernyshewskiy)

SPIVAK, M. A.

"Synthesis of automation with least number of states and given response" report submitted for the Intl. Symposium on Relay Systems and Finite Automata Theory (IFAC), Moscow, 24 Sep-2 Oct 1962.

PENZOV, YuYe.; RZHEKHINA, N.F.; GOKHMAN, A.V.; KABANOV, N.I.; KONOPLEVA, Yu.K.; LOSIK, M.V.; SPIVAK, M.A.; ZARETSKAYA, N.V., red.

[Problems in vector algebra] Sbornik zadach po vektornoi algebre. Saratov, Izd-vo Saratovskogo univ., 1964. 59 p. (MIRA 18:4)

L 18804-65 EWT(d)/T Ph-4 IJP(c)/AFMD(p)/RAEM(1)/RAEM(d)/ESD(dp)
ACCESSION NR: AT5000717 S/2582/64/000/012/0069/0097

AUTHOR: Spivak, M. A. (Saratov)

TITLE: Interpretation of the theory of automata by methods of the theory of proportions

SOURCE: Problemy\* kibernetiki, no. 12, 1964, 69-97

TOPIC TAGS: automata theory, logic circuit, abstract machine, homomorphism

ABSTRACT: An automata system is described as having three state descriptors X,S, and Y, which represent states of input, internal, and output devices, respectively. A state of an input device at a given moment, x(t), is determined by an external condition. The state of the internal device at a given moment, s(t), is a function of the state of the input device at that moment and a function of the state of the internal device at the preceding moment. The state of the output device s(t) is a function of the simultaneous state of the internal device. The author s(t) is a function of the simultaneous state of the internal device. The author considers the system of objects  $(x,S,Y,\sigma,\mu)$  to be an automat with input signal descriptor s(t), condition (state) descriptor s(t), output signal descriptor s(t), transition function s(t), and output function s(t). Several basic results of the abstract theory of automata are presented, with emphasis directed to the synthesis of an

Card 1/3

L 18804-65 ACCESSION NR: AT5000717

automaton according to given conditions. Preliminary treatment is accorded to notation and definitions within the automata theory. Binary relationships are symbolically defined for the operations of sectioning, projecting, transformation, product formation (union), and homologous union (reflective, symmetric, and transitive). Earlier work by S. Ginsburg (Some remarks on abstract machines, Trans. Amer. Math. Soc. 96, 3, 1960, 400-444) formed the basis of the theorem: "In order that an automat A be minimal it is necessary and sufficient that it be rigorously bound." The terminology is that of E. F. Mur (Umozritel!ny\*ye eksperimenty\* s posledovatel nostny mi mashinami, Sb. "Avtomaty" IL, M., 1956, 179-212). A minimal automat is described in terms of a minimal stable subset of SA. Necessary and sufficient conditions of a stable subset of SA are detailed and proved. The automat A, if not bound, contains components termed subautomats. These subautomats are minimal automats themselves if the necessary and sufficient rigorous bounding relationship is its equivalence relationship. Homomorphism of two automats is discussed, the conditions of its existence, and the properties of homomorphism are listed. An automat A is defined as a monomorphic specimen of sums of free automats. Homomorphism is also discussed in the context of automat reaction and in two related problems. The properties of the canonical form are given, and five theorems are stated and proved in the theory of automat synthesis. Card 2/3

### "APPROVED FOR RELEASE: 08/25/2000

### CIA-RDP86-00513R001652720012-5

L 18804-65
ACCESSION NR: AT5000717

Equivelence equations for relating systems of events to terminal automats are defined, and an example is worked out showing the sequence of formulas applied. Unions and intersections of event spaces are treated in a subsequent section. Orig. art. has: 19 theorems, and 1 figure.

ASSOCIATION: none

SUBMITTED: 21May62

SUB CODE: DP

NO REF SOV: 003

OTHER: 004

AUTHOR: Spivak, M. A. (Saratov)

TITLE: Algorithm of the abstract synthesis of automata for an expanded language of regular expressions

SOURGE: AN SSSR. Izvestiya. Tekhnicheskaya kibernetika, no. 1, 1965, 51-57

TOPIC TAGS: automaton, automaton synthesis

ABSTRACT: The problem is considered of the abstract synthesis of an automaton whose working conditions are written in the regular-expression language that contains, in addition to conventional symbols, the signs () and ' which denote intersection and supplementing of events. As the abstract-synthesis algorithm given by R. F. McNaughton et al. (IRE Trans., EC-9, 1960, no. 1) cannot be directly extended over the expanded regular-expression language, the author suggests a new algorithm based on an expansion of the regular expression into a

Card 1/2

L 44758-65 ACCESSION NR:	A P5007250	The state of the s	n que de la material	ganada di superinta yan da	0	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
,		Jaha Uhagig	''). It is als	so pointed o	ut that the ne	w
-1 withm narmil	S IDS INCIDATOR	<b>62 6 6 6 7</b>	rations in t	he future.	Orig. art.	
has: 4 figures as	nd 16 formulas.					
ASSOCIATION:	none					
SUBMITTED: 09	May64	ENCL: 0	0	SUB CODI	er DP	
NO REF SOV: 0		OTHER:	003			
050						
(3 543 Card 2/2						

Conditions for the decomposability of ratics into direct products.

Izv. vys. ucheb. zav.; mat. no.4:132-139 '65. (MTRA 18:9)

10993-66 EWT(d)/EWP(v)/EWP(k)/EWP(h)/EWP(1)AP5028529 ACC NR SOURCE CODE: UR/0286/65/000/020/0124/0124

INVENTOR: Smirnov, V. D.; Ushakov, V. N.; Spivak, M. A.; Gokhbaum, F. A.; Braylovskiy, M. I.; Astrova, T. I.

ORG: none

TITLE: Hydraulic cylinder for a high-capacity press. Class 58, No. 175823 announced by Experimental Construction bureau of the central scientific research institute of building construction (Eksperimental no-konstruktorskoye byuro tsentral nogo nauchno-

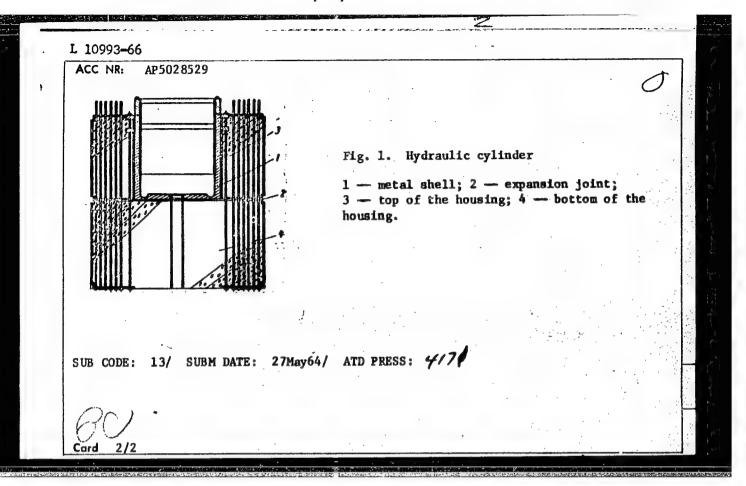
issledovatel' ekcgo instituta stroitel'nykh konstruktsiy)

SOURCE: Byulleten' izobreteniy i tovarnykh znakov, no. 20, 1965, 124

TOPIC TAGS: press, hydraulic press, high capacity press, press cylinder, cylinder design

ABSTRACT: This Author Certificate introduces a hydraulic cylinder for a high-capacity press. The cylinder (see Fig. 1) consists of inner metal shell 1, encased in a reinforced-concrete housing. Expansion joint 2 separates top 3 and bottom 4 of the housing to reduce the internal stresses. Orig. art. has: 1 figure.

1/2 Card



SPIVAK, M.A.

Base development of a regular expression and its applications.

Dokl. AN SSSR 162 no.3:520-522 My '65. (MIRA 18:5)

1. Saratovskiy gosudarstvennyy universitet im. N.G.Chernyshevskogo. Submitted December 3, 1964.

L 27898-66 EWT(d)/T/EWP(1) IJP(c) GG/BB
ACCESSION NR: AP5024537 UR/0378/65/000/004/0001/0011
519.95

10 B

AUTHOR

Spivak, N. A. H

TITLE: The algebraic characteristic of the calculational power of an automaton

SOURA B. Kibernetika, no. 4, 1965, 1-11

TOPIC TAGS: automaton, information processing, mathematic model, calculator, algebraic logic

ABSTRACT: The author defines an automaton as a discrete converter of information.

K. B. Krohn and J. L. Rhodes correctly defined in their paper (Proc. Sympos. Math. Theory Autom., New York, N. Y. 1962, Brooklyn N. Y., Polytechn, 1963, 341-384) the relative calculational power of automatons. However, the algebraic characteristic of the relative calculational power given by these authors is not correct. The basic aim of the present paper is the establishment of the correct algebraic characteristic of the relative calculational power of automatons. Following the definition of the mathematical model of the automaton and the characterization of the information conversion by means of the reaction concept, the author introduces the concept of reaction divisibility, extends this concept Card 1/2

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L 27898-66
ACCESSION NR: AP5024537

to sets of reactions, associates the sets with abstract semigroups, and introduces the concept of fitted semigroups representing (G, E) pairs (E - the set of equivalent relationships over the semigroup G). Such a fitted semigroup of the reaction set characterizes effectively the calculational power of the set of reactions. Orig. art. has: 125 formulas and 2 figures.

ASSOCIATION: none

SUBMITTED: 05Apr65 ENCL: 00 SUB CODE: DP, MA

NO REF SOV: 001 OTHER: 002

SPIVAK M.S., glavnyy redaktor; BELOZUB, V.G., redaktor; VASILENKO, P.M.,
redaktor; ZORIN, I.G., redaktor; IL'CHENKO, I.K., redaktor; KOVAL,
A.G., redaktor; KRYLOV, A.F., redaktor; PUKHAL'SKIY, A.V., redaktor;
SIDORRNKO, A.P., redaktor; FEDCHENKO, A.N., redaktor; ANGELINA, P.N.,
redaktor; BUZANOV, I.F., redaktor; BOYKO, D.V., redaktor; BURKATSKAYA,
G.Ye., redaktor; VASILENKO, A.A., redaktor; VIASYUK, P.A., redaktor;
GORODNIY, N.G., redaktor; DEMIDENKO, T.T., redaktor; DUBKOVETSKIY, F.I.,
redaktor; KIRICHENKO, F.G., redaktor; LITOVCHENKO, G.P., redaktor;
OZERNYY, M.Ye., redaktor; PERSHIN, P.N., redaktor; POPOV, F.A., redaktor;
POSMITNYY, M.A., redaktor; PSHENICHNYY, P.D., redaktor; RADCHENKO, B.P.,
redaktor; ROMANENKO, I.N., redaktor; RUBIN, S.S., redaktor; SAVCHENKO,
M.Kh., redaktor; SOKOLOVSKIY, A.N., redaktor; TSYBENKO, K.Ye., redaktor;
KOYAL'SKIY, V.F., tekhnicheskiy redaktor

[Practical collective farm encyclopedia] Kolkhoznaia proizvodstvennaia entsiklopediia. Izd.2-oe, ispr. i dop. Kiev. Gos.izd-vo sel\*khoz. lit-ry USSR. Vol.1. Abrikos - liutserna. 1956. 688 p. (MLRA 10:9)

(Agriculture-Dictionaries)